



CX2SM CRYSTAL

760 kHz to 1.35 MHz

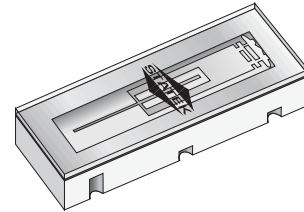
Low Profile Miniature Surface Mount Quartz Crystal

DESCRIPTION

The CX2SM quartz crystals are leadless devices designed for surface mounting on printed circuit boards or hybrid substrates. They are hermetically sealed in a rugged, miniature ceramic package. They are manufactured using the STATEK-developed photolithographic process, and were designed utilizing the experience acquired by producing millions of crystals for industrial, commercial, military and medical applications. Maximum process temperature should not exceed 260°C.

FEATURES

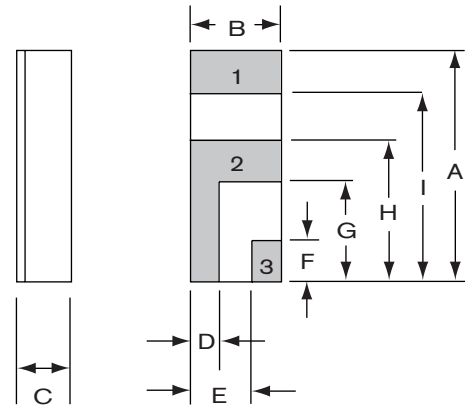
- Extensional mode
- Ideal for use with microprocessors
- Designed for low power applications
- Compatible with hybrid or PC board
- Low aging
- Full military testing available
- Ideal for battery operated applications
- Designed and manufactured in the USA



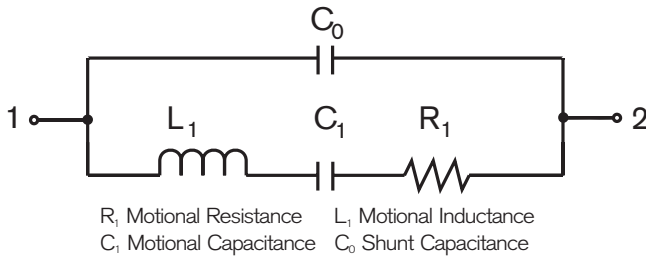
Glass Lid Shown

□ actual size
 □ side view

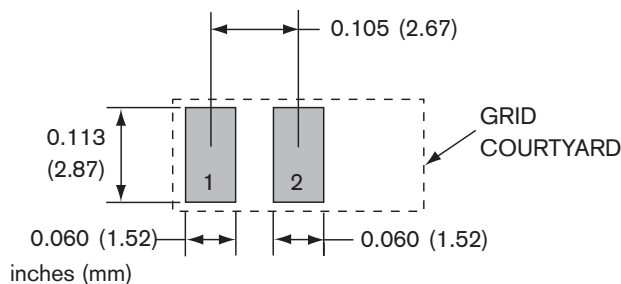
PACKAGE DIMENSIONS



EQUIVALENT CIRCUIT



SUGGESTED LAND PATTERN



DIM	TYP.		MAX.	
	inches	mm	inches	mm
A	0.260	6.60	0.275	6.99
B	0.094	2.39	0.108	2.74
C	-	-	see below	
D	0.035	0.89	0.045	1.14
E	0.059	1.50	0.069	1.75
F	0.050	1.27	0.060	1.52
G	0.105	2.67	0.115	2.92
H	0.155	3.94	0.165	4.19
I	0.210	5.33	0.220	5.59

DIM "C"	GLASS LID		CERAMIC LID	
	inches	mm	inches	mm
MAX	0.065	1.65	0.075	1.91
SM1	0.067	1.70	0.077	1.96
SM2	0.070	1.78	0.080	2.03

Note: Terminal 1 is electrically connected internally to terminal 3



SPECIFICATIONS

Specifications are typical at 25°C unless otherwise noted. Specifications are subject to change without notice.

Frequency Range	760 kHz - 1.35 MHz
Functional Mode	Extensional
Calibration Tolerance*	± 500 ppm (0.05%) ± 1000 ppm (0.1%) ± 10000 ppm (1.0%)
Load Capacitance	7 pF
Motional Resistance (R ₁)	5 kΩ MAX
Motional Capacitance (C ₁)	1.2fF
Quality Factor (Q)	150 k
Shunt Capacitance (C ₀)	1.0 pF
Drive Level	3 μW MAX
Turning Point (T ₀)**	35°C
Temperature Coefficient (k)	-0.035 ppm/°C ²
Aging, first year	5 ppm MAX
Shock, survival	1000 g peak, 0.3 ms, 1/2 sine
Vibration, survival	10 g RMS, 20-1,000 Hz random
Operating Temp. Range	-10°C to +70°C (Commercial) -40°C to +85°C (Industrial) -55°C to +125°C (Military)
Storage Temp. Range	-55°C to +125°C
Max Process Temperature	260°C for 20 sec.

Note: Frequency f at temperature T is related to frequency f₀ at turning point temperature T₀ by: $\frac{f-f_0}{f_0} = k(T-T_0)^2$

* Tighter frequency calibration available.
** Other turning points available.

TERMINATIONS

Designation	Termination
SM1	Gold Plated
SM2	Solder Plated
SM3	Solder Dipped

PACKAGING OPTIONS

CX2SM - Tray Pack
-16mm tape, 7" or 13" reels
(Reference tape and reel data sheet 10109)

HOW TO ORDER CX2SM CRYSTALS

CX2	S	C	SM1	—	1.0M,	500	/	M
Blank = Glass Lid C = Ceramic Lid		SM1 = Gold Plated SM2 = Solder Plated SM3 = Solder Dipped		Frequency K = kHz M = MHz		Calibration Tolerance @ 25°C (in ppm)		Operating Temp. Range: C = -10°C to +70°C I = -40°C to +85°C M = -55°C to +125°C S = Customer Specified
S if special or custom design. Blank if Std.								

TYPICAL APPLICATION FOR A PIERCE OSCILLATOR

The low profile CX miniature surface mount crystal is ideal for small, high density, battery operated portable products. The CX crystal designed in a Pierce oscillator (single inverter) circuit provides very low current consumption and high stability. A conventional CMOS Pierce oscillator circuit is shown below. The crystal is effectively inductive and in a PI-network circuit with C_D and C_G provides the additional phase shift necessary to sustain oscillation. The oscillation frequency (f₀) is 15 to 150 ppm above the crystal's series resonant frequency (f_S).

Drive Level

R_A is used to limit the crystal's drive level by forming a voltage divider between R_A and C_D. R_A also stabilizes the oscillator against changes in the amplifiers output resistance (R₀). R_A should be increased for higher voltage operation.

Load Capacitance

The CX crystal calibration tolerance is influenced by the effective circuit capacitances, specified as the load capacitance (C_L). C_L is approximately equal to:

$$C_L = \frac{C_D \times C_G}{C_D + C_G} + C_S \quad (1)$$

NOTE: C_D and C_G include stray layout to ground and C_S is the stray shunt capacitance between the crystal terminal. In practice, the effective value of C_L will be less than that calculated from C_D, C_G and C_S values because of the effect of the amplifier output resistance. C_S should be minimized.

The oscillation frequency (f₀) is approximately equal to:

$$f_0 = f_S \left[1 + \frac{C_1}{2(C_0 + C_L)} \right] \quad (2)$$

Where f_S = Series resonant frequency of the crystal
C₁ = Motional Capacitance
C₀ = Shunt Capacitance

CONVENTIONAL CMOS PIERCE OSCILLATOR CIRCUIT

